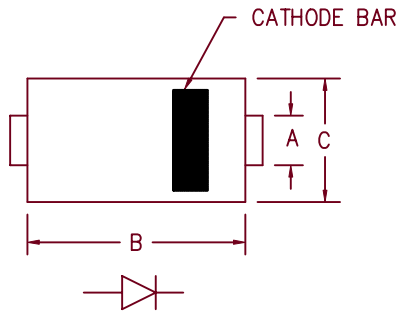
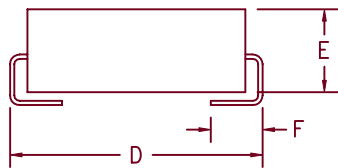


1 Amp Ultra Low Forward Voltage Schottky Diode LSM115J



Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.073	.087	1.85	2.21	
B	.160	.180	4.06	4.57	
C	.130	.155	3.30	3.94	
D	.205	.220	5.21	5.59	
E	.075	.130	1.91	3.30	
F	.030	.060	.760	1.52	



D0-214BA Package

Microsemi Catalog Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage
LSM115J	15V	15V

- Schottky Barrier Rectifier
- Guard Ring For Reverse Protection
- Low Power Loss, High Efficiency
- 100°C Junction Temperature
- VRRM 15V
- High Surge Capability
- Ultra Low Forward Voltage
- Schottky OR'ing diode

Electrical Characteristics

Average forward current	$I_F(AV)$ 1 Amps	$T_L = 65^\circ C$, Square wave, $R_{\theta JL} = 15^\circ C/W$
Maximum surge current	I_{FSM} 50 Amps	8.3ms, half sine, $T_J = 100^\circ C$
Maximum peak forward voltage	V_{FM} 0.29 Volts	$I_{FM} = 1.0A$; $T_J = 25^\circ C^*$
Maximum peak reverse current	I_{RM} 500 mA	$V_{RRM} = 15V$, $T_J = 100^\circ C$
Maximum peak reverse current	I_{RM} 200 mA	$V_R = 5V$, $T_J = 100^\circ C$
Maximum peak reverse current	I_{RM} 100 mA	$V_R = 3.3V$, $T_J = 100^\circ C$
Maximum peak reverse current	I_{RM} 10 mA	$V_{RRM} = 15V$, $T_J = 25^\circ C$
Typical junction capacitance	C_J 120pF	$T_J = 25^\circ C$, $V_R = 5V$

*Pulse test: Pulse width 300 μ sec. Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range	T_{STG}	$-55^\circ C$ to $150^\circ C$
Operating junction temp range	T_J	$-55^\circ C$ to $100^\circ C$
Maximum thermal resistance	$R_{\theta JL}$	$15^\circ C/W$ Junction to Lead
Weight		.0047 ounces (.013 grams) typical

4-3-00 Rev. 2

LSM115J

Figure 1
Typical Forward Characteristics

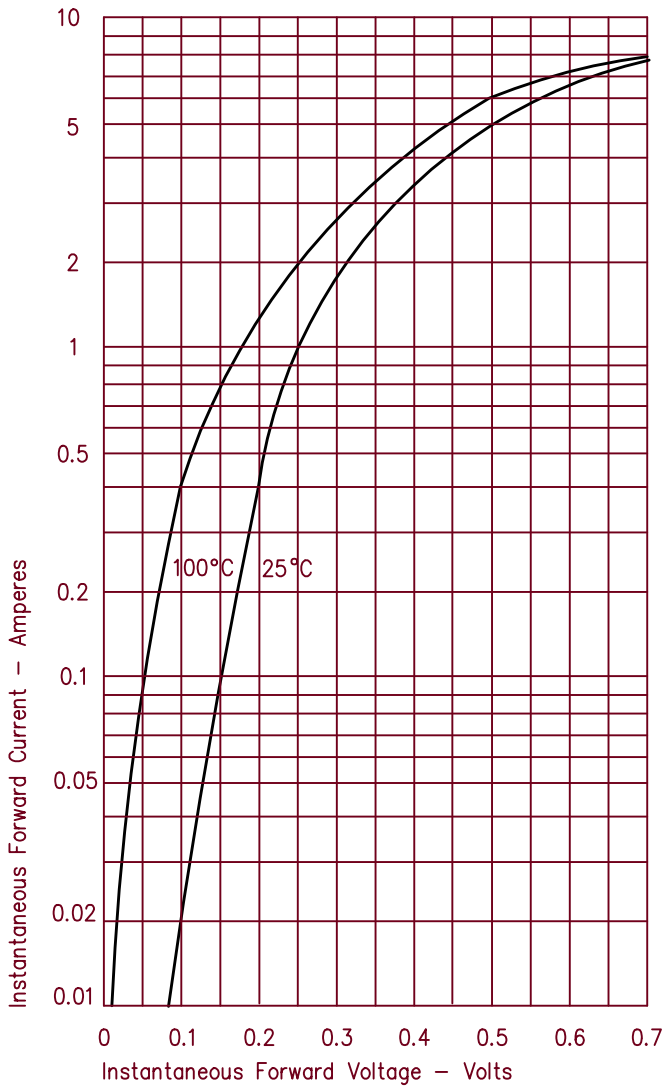


Figure 3
Typical Junction Capacitance

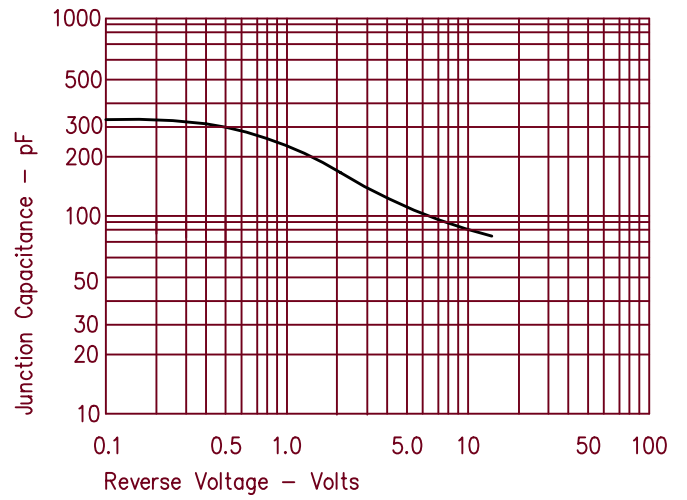
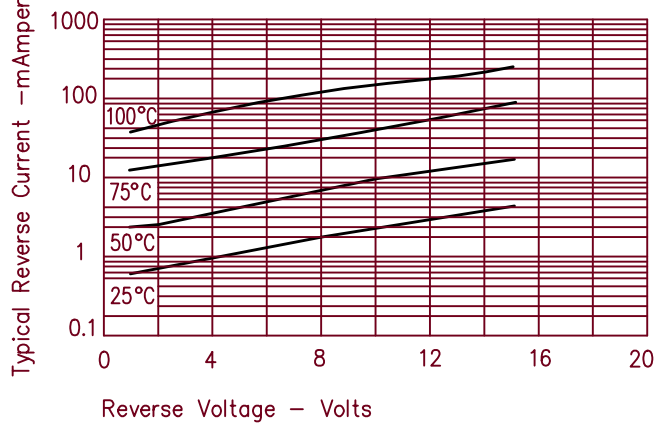


Figure 2
Typical Reverse Characteristics



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